300 mA LDO Regulator, Low Dropout Voltage, Ultra Low Noise, High PSRR with Power Good

Product Preview NCV8164C

The NCV8164C is a 300 mA LDO, next generation of high PSRR, ultra–low noise and low dropout regulators with Power Good open collector output. Designed to meet the requirements of RF and sensitive analog circuits, the NCV8164C device provides ultra–low noise, high PSRR and low quiescent current. The device also offer excellent load/line transients. The NCV8164C is designed to work with a 1 μ F input and a 1 μ F output ceramic capacitor. It is available in industry standard TSOP–5, WDFNW6 0.65P, 2 mm x 2 mm and DFNW8 0.65P, 3 mm x 3 mm.

Features

- Operating Input Voltage Range: 1.6 V to 5.0 V
- Available in Fixed Voltage Option: 1.2 V to 4.5 V
- Adjustable Version Reference Voltage: 1.2 V
- ±2% Accuracy Over Load and Temperature
- Ultra Low Quiescent Current Typ. 30 µA
- Standby Current: Typ. 0.1 µA
- Very Low Dropout: 110 mV at 300 mA for 3.3 V Variant
- Ultra High PSRR: Typ. 85 dB at 10 mA, f = 1 kHz
- Ultra Low Noise: 9 µV_{RMS} (Fixed Version)
- Stable with a 1 µF Small Case Size Ceramic Capacitors
- Available in TSOP–5 3 mm x 1.5 mm x 1 mm CASE 483
 - WDFNW6 2 mm x 2 mm x 0.75 mm CASE 511DW
 - DFNW8 3 mm x 3 mm x 0.9 mm CASE 507AD
- NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements
- AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

Typical Applications

- Communication Systems
- In–Vehicle Networking
- Telematics, Infotainment and Clusters
- General Purpose Automotive

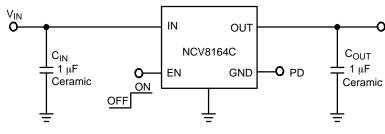
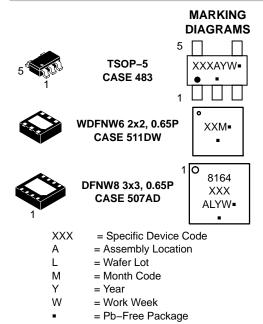


Figure 1. Typical Application Schematic

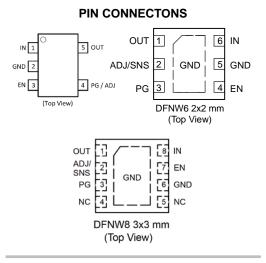


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(Note: Microdot may be in either location)



ORDERING INFORMATION

See detailed ordering and shipping information on page 8 of this data sheet.

This document contains information on a new product. Specifications and information herein are subject to change without notice.

Table 1. PIN FUNCTION DESCRIPTION

Pin No. TSOP-5	Pin No. WDFNW6	Pin No. DFNW8	Pin Name	Description
1	6	8	IN	Input voltage supply pin
5	1	1	OUT	Regulated output voltage. The output should be bypassed with small 1 μF ceramic capacitor
3	4	7	EN	Chip enable: Applying V_{EN} < 0.2 V disables the regulator, Pulling V_{EN} > 0.7 V enables the LDO
4 / -	3	3	PG	Power Good, open collector. Use 10 $k\Omega$ to 100 $k\Omega$ pull–up resistor connected to output or input voltage
2	5	6	GND	Common ground connection
- / 4	2	2	ADJ	Adjustable output feedback pin (for adjustable version only)
-	2	2	SNS	Sense feedback pin. Must be connected to OUT pin on PCB (for fixed versions only)
-	-	4, 5	N/C	Not connected, pin can be tied to ground plane for better power dissipation
_	EPAD	EPAD	EPAD	Expose pad should be tied to ground plane for better power dissipation

Table 2. ABSOLUTE MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Input Voltage (Note 1)	V _{IN}	-0.3 to 5.3	V
Output Voltage	V _{OUT}	–0.3 to V _{IN} +0.3, max. 5.3	V
Chip Enable Input	V _{CE}	-0.3 to 5.3	V
Power Good Voltage	V _{PG}	-0.3 to 5.3	V
Power Good Current	I _{PG}	30	mA
Output Short Circuit Duration	tsc	unlimited	S
Maximum Junction Temperature	TJ	150	°C
Storage Temperature	T _{STG}	-55 to 150	°C
ESD Capability, Human Body Model (Note 2)	ESD _{HBM}	2000	V
ESD Capability, Charged Device Model (Note 2)	ESD _{CDM}	1000	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.
Refer to ELECTRICAL CHARACTERISTIS and APPLICATION INFORMATION for Safe Operating Area.
This device series incorporates ESD protection and is tested by the following methods: ESD Human Body Model tested per AEC-Q100-002 (EIA/JESD22-A114) ESD Charged Device Model tested per EIA/JESD22-C101, Field Induced Charge Model

Table 3. THERMAL CHARACTERISTICS

Rating	Symbol	Value	Unit
THERMAL CHARACTERISTICS, TSOP-5 PACKAGE			•
Thermal Resistance, Junction-to-Ambient (Note 3)	$R_{ hetaJA}$	158	°C/W
Thermal Resistance, Junction-to-Case (top)	R _{0JC(top)}	155	°C/W
Thermal Resistance, Junction-to-Case (bottom) (Note 4)	R _{θJC(bot)}	102	°C/W
Thermal Resistance, Junction-to-Board	R _{θJB}	197	°C/W
Characterization Parameter, Junction-to-Top	Ψ_{JT}	40	°C/W
Characterization Parameter, Junction-to-Board	Ψ_{JB}	82	°C/W
THERMAL CHARACTERISTICS, WDFNW6-2X2, 0.65 PITCH PACKAG)E		-
Thermal Resistance, Junction-to-Ambient (Note 3)	$R_{ ext{ heta}JA}$	51	°C/W
Thermal Resistance, Junction-to-Case (top)	R _{0JC(top)}	142	°C/W
Thermal Resistance, Junction-to-Case (bottom) (Note 4)	R _{θJC(bot)}	2.0	°C/W
Thermal Resistance, Junction-to-Board	$R_{\theta JB}$	117	°C/W
Characterization Parameter, Junction-to-Top	Ψ_{JT}	1.9	°C/W
Characterization Parameter, Junction-to-Board	Ψ_{JB}	7.7	°C/W
THERMAL CHARACTERISTICS, DFNW8-3X3, 0.65 PITCH PACKAGE			
Thermal Resistance, Junction-to-Ambient (Note 3)	$R_{ extsf{ heta}JA}$	50	°C/W
Thermal Resistance, Junction-to-Case (top)	R _{0JC(top)}	142	°C/W
Thermal Resistance, Junction-to-Case (bottom) (Note 4)	R _{0JC(bot)}	7.9	°C/W
Thermal Resistance, Junction-to-Board	R _{θJB}	125	°C/W
Characterization Parameter, Junction-to-Top	Ψ_{JT}	2.0	°C/W
Characterization Parameter, Junction-to-Board	Ψ_{JB}	7.5	°C/W

The junction-to-ambient thermal resistance under natural convection is obtained in a simulation on a high-K board, following the JEDEC51.7 guidelines with assumptions as above, in an environment described in JESD51-2a.
 The junction-to-case (bottom) thermal resistance is obtained by simulating a cold plate test on the IC exposed pad. Test description can be found in the ANSI SEMI standard G30-88.

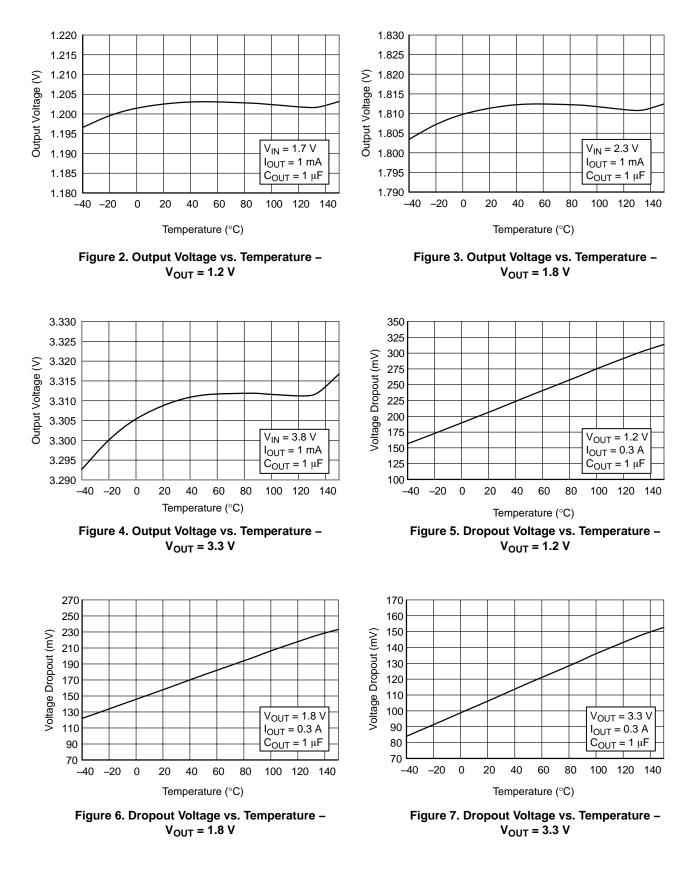
$\textbf{Table 4. ELECTRICAL CHARACTERISTICS} (-40^{\circ}C \leq T_{J} \leq 150^{\circ}C; \ V_{IN} = V_{OUT(NOM)} + 0.5 \ V; \ I_{OUT} = 1 \ \text{mA}, \ C_{IN} = C_{OUT} + C_{O$	-
= 1 μ F, V _{EN} = V _{IN} , unless otherwise noted. Typical values are at T_J = +25°C (Note 5))	

Parameter	Test Conditions		Symbol	Min	Тур	Max	Unit
Operating Input Voltage			V _{IN}	1.6		5.0	V
Output Voltage Accuracy	$\label{eq:VIN} \begin{array}{l} V_{IN} = V_{OUT(NOM)} + 0.5 \text{ V to } 5.0 \text{ V}, \\ 0.1 \text{ mA} \leq I_{OUT} \leq 300 \text{ mA} \end{array}$		V _{OUT}	-2		+2	%
Reference Voltage (Adjustable Ver. ADJ pin connected to OUT)	V _{IN} = 1.6 \ 0.1 mA ≤ I _{OU}		V _{ADJ}	1.176	1.2	1.224	V
Line Regulation	V _{OUT(NOM)} + 0.5	$V \le V_{IN} \le 5.0 V$	Line _{Reg}		0.5		mV/V
Load Regulation	I _{OUT} = 1 mA	to 300 mA	Load _{Reg}		2		mV
Dropout Voltage (Note 6)	I _{OUT} = 300 mA	V _{OUT(NOM)} = 1.5 V	V _{DO}		170	295	mV
TSOP–5, WDFNW6		V _{OUT(NOM)} = 1.8 V			155	255	
		$V_{OUT(NOM)} = 2.5 V$			125	200	
		V _{OUT(NOM)} = 2.8 V			115	185	
		V _{OUT(NOM)} = 3.0 V			113	177	
		V _{OUT(NOM)} = 3.3 V			110	170	
		V _{OUT(NOM)} = 4.5 V			95	135	
Dropout Voltage (Note 6)	I _{OUT} = 300 mA	V _{OUT(NOM)} = 1.5 V	V _{DO}		180	315	mV
DFNW8		V _{OUT(NOM)} = 1.8 V			165	275	
		V _{OUT(NOM)} = 2.5 V			140	220	1
		V _{OUT(NOM)} = 2.8 V			130	205	
		V _{OUT(NOM)} = 3.0 V			127	197	
		V _{OUT(NOM)} = 3.3 V			125	190	
		V _{OUT(NOM)} = 4.5 V			112	170	
Output Current Limit	V _{OUT} = 90%	V _{OUT(NOM)}	I _{CL}	350	560		mA
Short Circuit Current	V _{OUT}		I _{SC}		580		
Quiescent Current	I _{OUT} =	0 mA	Ι _Q		30	40	μA
Shutdown Current	V _{EN} ≤	0.4 V	I _{DIS}		0.01	1.5	μΑ
EN Pin Threshold Voltage	EN Input V	V _{ENH}	0.7			V	
	EN Input V	V _{ENL}			0.2		
EN Pull Down Current	V _{EN} =	V _{EN} = 5.0 V			0.2	0.6	μA
Power Good Threshold Voltage	Output Volta	V _{PGUP}		95		%	
	Output Volt	V _{PGDW}		90			
Power Good Output Voltage Low	I _{PG} = 5 mA, Open drain		V _{PGLO}			0.3	V
Turn–On Time (Note 7)	C _{OUT} = 1 μF, From assertion of V _{EN} to V _{OUT} = 95% V _{OUT(NOM)}				120		μs
Power Supply Rejection Ratio	V _{OUT(NOM)} = 3.3 V,	f = 100 Hz	P _{SRR}		83		dB
(Note 7)	$I_{OUT} = 10 \text{ mA}$	f = 1 kHz			85		
		f = 10 kHz			80	1	
		f = 100 kHz	1		61	1	
Output Voltage Noise (Fixed Ver.)	f = 10 Hz to 100 kHz				9		μV _{RMS}
		V _N	<u> </u>			°C	
Thermal Shutdown Threshold	Temperat	ure rising	T _{SDH}		165		-0
Thermal Shutdown Threshold (Note 7)	Temperat Temperature	5	T _{SDH} T _{HYST}		165 15		°C

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

5. Performance guaranteed over the indicated operating temperature range by design and/or characterization. Production tested at T_J = T_A = 25°C.
 6. Low duty cycle pulse techniques are used during the testing to maintain the junction temperature as close to ambient as possible. Dropout voltage is characterized when V_{OUT} falls 3% below V_{OUT(NOM)}.
 7. Guaranteed by design and characterization.

TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS (continued)

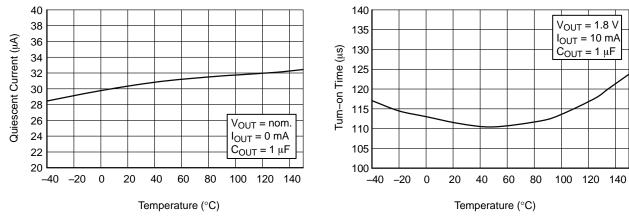


Figure 8. Quiescent Current va Temperature



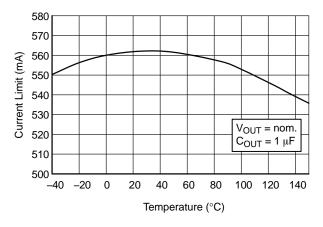


Figure 10. Current Limit vs. Temperature

96,0

95,0

^oower Good Thresholds (%)

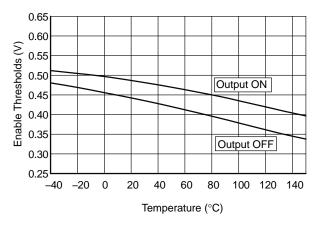
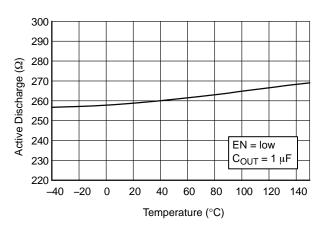


Figure 11. Enable Thresholds vs Temperature





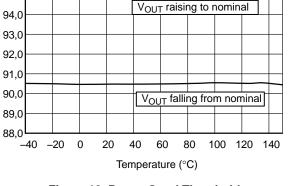
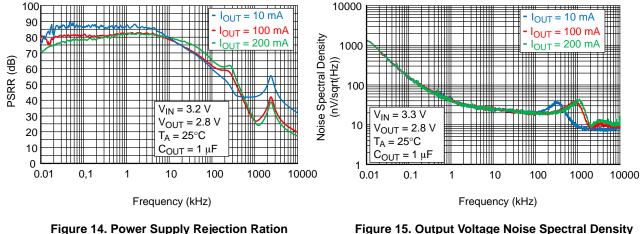


Figure 12. Power Good Threshold vs. Temperature

TYPICAL CHARACTERISTICS (continued)



for $V_{OUT} = 2.8 V$, $C_{OUT} = 1 \mu F$

Figure 15. Output Voltage Noise Spectral Density for V_{OUT} = 2.8 V, C_{OUT} = 1 μ F

APPLICATIONS INFORMATION

The NCV8164C is the member of new family of high output current and low dropout regulators which delivers low quiescent and ground current consumption, good noise and power supply ripple rejection ratio performance. The NCV8164C incorporates EN pin and power good output for simple controlling by MCU or logic. Standard features include current limiting, soft–start feature and thermal protection.

Input Decoupling (CIN)

It is recommended to connect at least 1 μ F ceramic X5R or X7R capacitor between IN and GND pin of the device. This capacitor will provide a low impedance path for any unwanted AC signals or noise superimposed onto constant input voltage. The good input capacitor will limit the influence of input trace inductances and source resistance during sudden load current changes. Higher capacitance and lower ESR capacitors will improve the overall line transient response.

Output Decoupling (COUT)

The NCV8164C does not require a minimum Equivalent Series Resistance (ESR) for the output capacitor. The device is designed to be stable with standard ceramics capacitors with values of 1 μ F or greater. The X5R and X7R types have the lowest capacitance variations over temperature thus they are recommended.

Power Good Output Connection

The NCV8164C include Power Good functionality for better interfacing to MCU system. Power Good output is open collector type, capable to sink up to 10 mA. Recommended operating current is between 10 μ A and 1 mA to obtain low saturation voltage. External pull–up resistor can be connected to any voltage up to 5.0 V (please see Absolute Maximum Ratings table).

Power Dissipation and Heat Sinking

The maximum power dissipation supported by the device is dependent upon board design and layout. Mounting pad configuration on the PCB, the board material, and the ambient temperature affect the rate of junction temperature rise for the part. For reliable operation junction temperature should be limited to +125°C, however device is capable to work up to junction temperature +150°C. The maximum power dissipation the NCV8164C can handle is given by:

$$P_{D(MAX)} = \frac{\left[T_{J(MAX)} - T_{A}\right]}{R_{\theta JA}}$$
(eq. 1)

The power dissipated by the NCV8164C for given application conditions can be calculated from the following equations:

$$\mathsf{P}_\mathsf{D} \approx \mathsf{V}_\mathsf{IN}(\mathsf{I}_\mathsf{GND}(\mathsf{I}_\mathsf{OUT})) + \mathsf{I}_\mathsf{OUT}\,(\mathsf{V}_\mathsf{IN} - \mathsf{V}_\mathsf{OUT}) \qquad (\mathsf{eq. 2})$$

or

$$V_{IN(MAX)} \approx \frac{P_{D(MAX)} + (V_{OUT} \times I_{OUT})}{I_{OUT} + I_{GND}}$$
 (eq. 3)

Hints

VIN and GND printed circuit board traces should be as wide as possible. When the impedance of these traces is high, there is a chance to pick up noise or cause the regulator to malfunction. Place external components, especially the output capacitor, as close as possible to the NCV8164C, and make traces as short as possible.

Adjustable Version

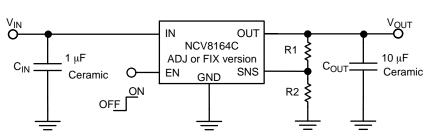
Not only adjustable version, but also any fixed version can be used to create adjustable voltage, where original fixed voltage becomes reference voltage for resistor divider and feedback loop. Output voltage can be equal or higher than original fixed option, while possible range is from 1.2 V up to 4.5 V. Figure 16 shows how to add external resistors to increase output voltage above fixed value.

 $V_{OUT} = V_{FIX} \times (1 + R1/R2)$

Output voltage is then given by equation

where V_{FIX} is voltage of original fixed version (from 1.2 V up to 4.5 V) or adjustable version (1.2 V). Do not operate the device at output voltage about 4.7 V, as device can be damaged.

In order to avoid influence of current flowing into SNS pin to output voltage accuracy (SNS current varies with voltage option and temperature, typical value is 300 nA) it is recommended to use values of R1 and R2 below 500 k Ω .



(eq. 4)

Figure 16. Adjustable Variant Application

Please note that output noise is amplified by V_{OUT} / V_{FIX} ratio. For example, if original 1.2 V fixed variant is used to create 3.6 V output voltage, output noise is increased 3.6 / 1.2 = 3 times and real value will be $3 \times 9 \,\mu Vrms = 27 \,\mu Vrms$. For noise sensitive applications it is recommended to use as

high fixed variant as possible – for example in case above it is better to use 3.3 V fixed variant to create 3.6 V output voltage, as output noise will be amplified only $3.6 / 3.3 = 1.09 \times (9.8 \,\mu\text{Vrms})$.

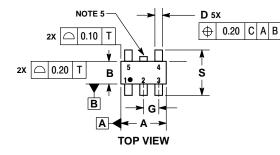
Device Part No.	Wafer Part	Marking	Package Option	Package	Shipping †
NCV8164CSN180T1G	A0C00HJ-FNT8	EJ	N/A	TSOP5 (Pb–Free)	3000 / Tape & Reel
NCV8164CSN280T1G	A0C00HH-FNT8	EK	N/A	TSOP5 (Pb–Free)	3000 / Tape & Reel
NCV8164CSNADJT1G	A0C00HP-FNT8	E4	N/A	TSOP5 (Pb–Free)	3000 / Tape & Reel
NCV8164CMTW180TAG	A0C00HJ-FNT8	FJ	Wettable	WDFNW6 2 x 2 (WF, Pb–Free)	3000 / Tape & Reel
NCV8164CMTW280TAG	A0C00HH-FNT8	FK	Wettable	WDFNW6 2 x 2 (WF, Pb–Free)	3000 / Tape & Reel
NCV8164CMTW290TAG	A0C00HK-FNT8	FH	Wettable	WDFNW6 2 x 2 (WF, Pb–Free)	3000 / Tape & Reel
NCV8164CMTWADJTAG	A0C00HP-FNT8	F2	Wettable	WDFNW6 2 x 2 (WF, Pb–Free)	3000 / Tape & Reel
NCV8164CAMLADJTCG	A0C00HP-FNT8	G2	Wettable	DFNW8 3 x 3 (WF, Pb–Free)	3000 / Tape & Reel

ORDERING INFORMATION

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

TSOP-5 **CASE 483** ISSUE M



SIDE VIEW

□ 0.05

С



DETAIL Z

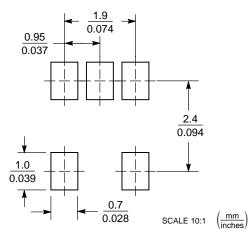
END VIEW

NOTES:

NOTES:
 DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 CONTROLLING DIMENSION: MILLIMETERS.
 MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
 DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE. DIMENSION A.
 OPTIONAL CONSTRUCTION: AN ADDITIONAL TRIMMED LEAD IS ALLOWED IN THIS LOCATION. TRIMMED LEAD NOT TO EXTEND MORE THAN 0.2 FROM BODY.

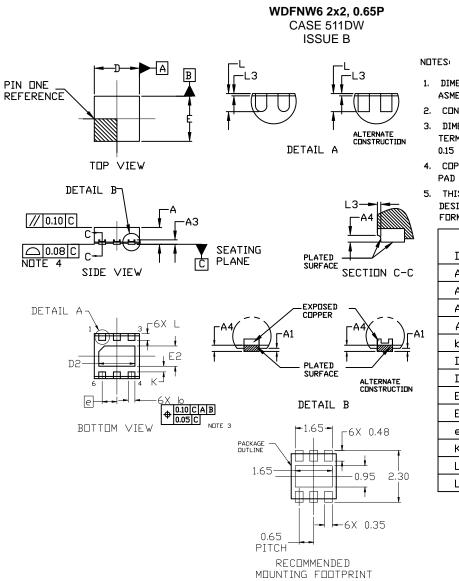
	MILLIMETERS					
DIM	MIN MAX					
Α	2.85	3.15				
В	1.35	1.65				
c	0.90	1.10				
D	0.25	0.50				
G	0.95 BSC					
Н	0.01	0.10				
L	0.10	0.26				
ĸ	0.20	0.60				
м	0 °	10 °				
s	2.50	3.00				

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

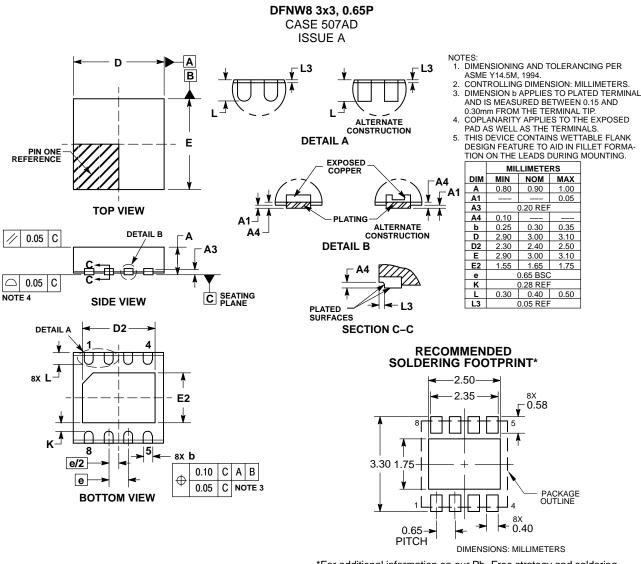
PACKAGE DIMENSIONS



- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- 3. DIMENSION 6 APPLIES TO PLATED TERMINALS AND IS MEASURED BETWEEN 0.15 AND 0.30MM FROM THE TERMINAL TIP.
- 4. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.
- 5. THIS DEVICE CONTAINS WETTABLE FLANK DESIGN FEATURES TO AID IN FILLET FORMATION ON THE LEADS DURING MOUNTING.

	MILLIMETERS			
DIM	MIN.	NDM.	MAX.	
Α	0.70	0.75	0.80	
A1			0.05	
A3	l	0.20 REF	-	
A4	0.10			
b	0.25	0.30	0.35	
D	1.90	2.00	2.10	
D2	1.50	1.60	1.70	
Е	1.90	2.00	2.10	
E2	0.80	0.90	1.00	
e	0.65 BSC			
к	0.25 REF			
L	0.25	0.30	0.35	
L3	0.05 REF			

PACKAGE DIMENSIONS



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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